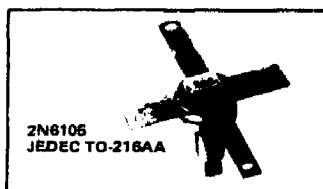


RF Power Transistors

**2N6104
 2N6105**



**30-W 400-MHz Broadband
 Emitter-Ballasted Silicon
 N-P-N Overlay Transistors**

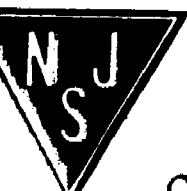
Features:

- 5-dB gain (min.) at 400 MHz with 30 watts (min.) output
- Emitter-ballasting resistors
- Broadband performance (225-400 MHz)
- Low-inductance ceramic-metal hermetic package
- Radial leads for microstripline circuits
- All electrodes isolated from the stud (2N6105)
- Flange is emitter lead (2N6104)

MAXIMUM RATINGS, Absolute-Maximum Values:

* COLLECTOR-TO-EMITTER VOLTAGE:			
With base open	V_{CEO}	30	V
* COLLECTOR-TO-BASE VOLTAGE			
	V_{CBO}	65	V
* EMITTER-TO-BASE VOLTAGE			
	V_{EBO}	4	V
* CONTINUOUS COLLECTOR CURRENT			
	I_C	4.5	A
* TRANSISTOR DISSIPATION			
	P_T		
At case temperatures up to 75° C		36	W
At case temperatures above 75° C		Derate linearly at 0.288	W/°C
* TEMPERATURE RANGE:			
Storage & Operating (Junction)		- 65 to +200	°C
* CASE TEMPERATURE (During soldering):			
For 10 s max.		230	°C

* In accordance with JEDEC registration data format JS-6 RDF-3/JS-9 RDF-7.



NJ Semi-Conductors reserves the right to change test conditions, parameters limits and package dimensions without notice information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

2N6104, 2N6105

ELECTRICAL CHARACTERISTICS, at Case Temperature (T_C) = 25°C unless otherwise specified
STATIC

CHARACTERISTIC	SYMBOL	TEST CONDITIONS				LIMITS		UNITS
		DC Voltage V		DC Current mA		MIN.	MAX.	
		V _{CE}	V _{BE}	I _E	I _C			
* Collector-to-Emitter Cutoff Current: Base connected to emitter, $T_C=55^\circ\text{C}$	I _{CES}	30	0			—	10	mA
* Collector-to-Emitter Breakdown Voltage: With base connected to emitter	V _{(BR)CES}		0		200 ^a	65	—	V
With base open	V _{(BR)CEO}				200 ^a	30	—	
* Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}			5	0	4	—	V
* Thermal Resistance (Junction-to-Case)	R _{θJC}						3.5	°C/W

^aPulsed through a 25-mH inductor; duty factor = 50%.

DYNAMIC

CHARACTERISTIC	SYMBOL	TEST CONDITIONS				LIMITS		UNITS
		DC Collector Supply (V _{CC})-V	Input Power (P _{IE})-W	Output Power (P _{OE})-W	Frequency (f)-MHz	Min.	Max.	
Output Power (See Fig. 10)	P _{OE}	28	9.5		400	30	—	W
Overdrive Test (See Fig. 10)	P _{OE0}	28	12.0		400	34	—	
* Power Gain	G _{PE}	28		30	400	5	—	dB
* Collector Efficiency	η _C	28	9.5		400	65	—	%
* Collector-to-Base Output Capacitance	C _{obo}	30 (V _{CB})			1	—	35	pF

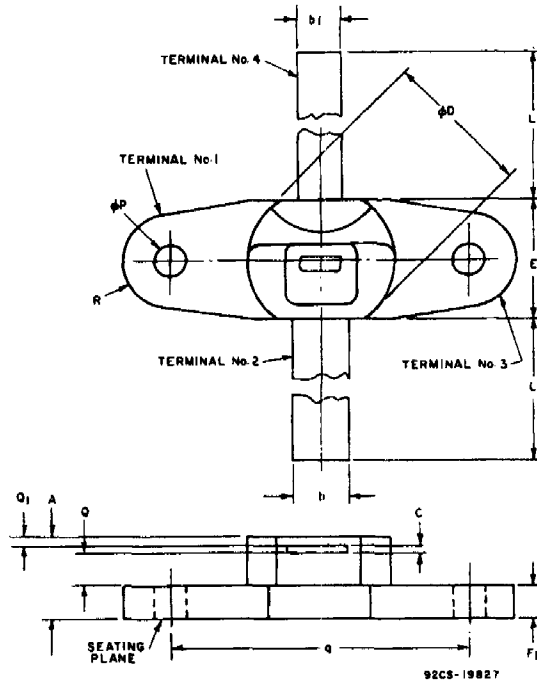
* In accordance with JEDEC registration data format JS-6 RDF-3/JS-9 RDF-7.

TYPICAL APPLICATION INFORMATION

CIRCUIT	COLLECTOR SUPPLY VOLTAGE (V _{CC})-V	OUTPUT POWER (P _{OE})-W	INPUT POWER (P _{IE})-W	COLLECTOR EFFICIENCY (η _C)-%	FIG. NO.
225-400 MHz (2N6105) [▲] Broadband Amplifier	28	30	5 - 7.5	69 - 77	13
	20	20	5 - 7	70 - 82	13
400 MHz (2N6104-5) Narrow-Band Amplifier	28	34	9.5	78	10
225-400 MHz (2N6105) [▲] Push-Pull Amplifier	28	60	11.5 - 18	72 - 84	16

[▲] Similar performance can be obtained with the 2N6104.

DIMENSIONAL OUTLINE FOR 2N6104
RCA HF-32



SYMBOL	INCHES		MILLIMETERS		NOTES	
	MIN.	MAX.	MIN.	MAX.		
A	0.160	0.210	4.07	5.33	1	
b	0.135	0.145	3.429	3.683		
b ₁	0.088	0.108	2.413	2.687		
c	0.004	0.010	0.102	0.254		
φD	0.305	0.320	7.75	8.12		
E	0.275	0.300	6.99	7.62		
F ₁	0.057	0.067	1.446	1.701		
L	0.456	0.510	11.56	12.96		
φP	0.115	0.125	2.921	3.175		
Q	0.085	0.105	2.16	2.68		
Q ₁	-	-	-	-		2
q	0.590	0.610	14.99	15.48		
R	0.115	0.125	2.921	3.175		

NOTES:
1. TYPICAL TWO LEADS.
2. BODY CONTOUR OPTIONAL WITHIN Q₁, φD, AND E.

TERMINAL CONNECTIONS

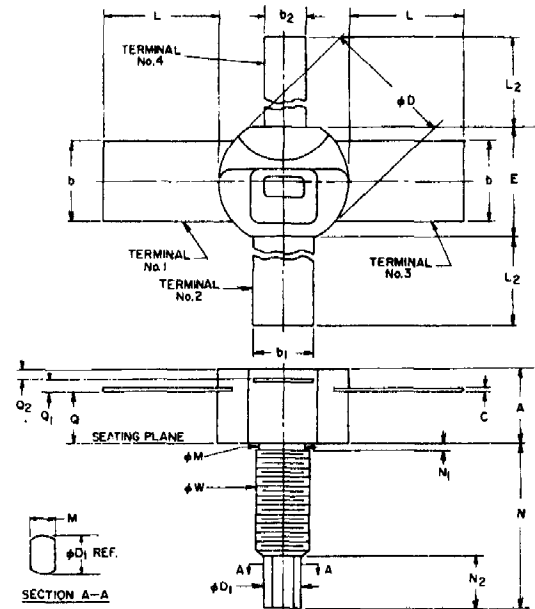
2N6104:

Flange (Terminals 1,3) - Emitter
Terminal 2 - Base
Terminal 4 - Collector

2N6105:

Terminals 1,3 - Emitter
Terminal 2 - Base
Terminal 4 - Collector

DIMENSIONAL OUTLINE FOR 2N6105
JEDEC TO-216



9255-376,394

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	0.150	0.230	3.81	5.84	-
b	0.195	0.205	4.953	5.207	-
b ₁	0.135	0.145	3.429	3.683	-
b ₂	0.095	0.105	2.413	2.687	-
C	0.004	0.010	0.102	0.254	3
φD	0.305	0.320	7.75	8.12	5
φD ₁	0.110	0.130	2.80	3.30	1
E	0.275	0.300	6.99	7.62	5
L	0.285	0.290	6.74	7.38	-
L ₂	0.455	0.510	11.56	12.96	-
M	0.053	0.064	1.35	1.62	-
φM	0.120	0.163	3.05	4.14	-
N	0.425	0.470	10.80	11.93	-
N ₁	-	0.078	-	1.98	4
N ₂	0.110	0.150	2.80	3.81	-
Q	0.120	0.170	3.05	4.31	-
Q ₁	0.025	0.045	0.64	1.14	-
Q ₂	-	-	-	-	5
φW	-	-	-	-	2

Millimeter dimensions are derived from original inch dimensions

NOTES:

- 0.053 - 0.064 INCH (1.35 - 1.62 mm) WRENCH FLAT.
- PITCH DIA. OF 8-32 UNC-2A COATED THREADS (REF. UNITED SCREW THREADS ANS B1.1 - 1960). THE APPLIED TORQUE SHOULD NOT EXCEED 5 IN.-LBS. CLAMPING FORCES MUST BE APPLIED ONLY TO THE FLAT SURFACES OF THE STUD.
- TYPICAL FOR ALL LEADS.
- LENGTH OF INCOMPLETE OR UNDERCUT THREADS OF φW.
- BODY CONTOUR OPTIONAL WITHIN Q₂, φD, AND E.